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AOD417

P-Channel Enhancement Mode MOSFET

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Features

■ -30V, -30A, $R_{DS(ON)}$ =32mΩ @V_{GS} = -10V.
$R_{DS(ON)}$ =50mΩ @V_{GS} = -4.5V.

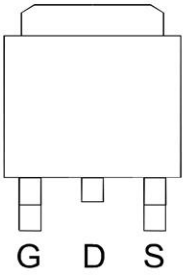
Application

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable
- Electronics
- Logic Level Shift

Package and Pin Configuration

(TO-252)

Top View



1. GATE
2. DRAIN
3. SOURCE

Marking:

ABSOLUTE MAXIMUM RATINGS T_C = 25°C unless otherwise noted

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous @ T_C = 25°C	I_D	-30	A
@ T_C = 100°C		-21	A
Drain Current-Pulsed [a]	I_{DM}	-120	A
Maximum Power Dissipation @ T_C = 25°C	P_D	50	W
- Derate above 25°C		0.33	W/°C
Operating and Store Temperature Range	T_J,T_{stg}	-55 to 175	°C

Thermal Characteristics

Parameter	Symbol	Limit	Units
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} = 0V, I_D = -250μA	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = -24V, V_{GS} = 0V			-1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	V_{GS} = 20V, V_{DS} = 0V			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	V_{GS} = -20V, V_{DS} = 0V			-100	nA
On Characteristics [c]						
Gate Threshold Voltage	$V_{GS(th)}$	V_{GS} = V_{DS}, I_D = -250μA	-1		-3	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS} = -10V, I_D = -5.3A		27	32	mΩ
		V_{GS} = -4.5V, I_D = -2A		38	50	mΩ
Dynamic Characteristics [d]						
Input Capacitance	C_{iss}	V_{DS} = -15V, V_{GS} = 0V, f = 1.0 MHz		1130		pF
Output Capacitance	C_{oss}			220		pF
Reverse Transfer Capacitance	C_{rss}			180		pF
Switching Characteristics [d]						
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = -15V, I_D = -1A, V_{GS} = -10V, R_{GEN} = 6Ω		14	28	ns
Turn-On Rise Time	t_r			6	12	ns
Turn-Off Delay Time	$t_{d(off)}$			40	80	ns
Turn-Off Fall Time	t_f			10	20	ns
Total Gate Charge	Q_g	V_{DS} = -15V, I_D = -5.3A, V_{GS} = -10V		24	31	nC
Gate-Source Charge	Q_{gs}			3		nC
Gate-Drain Charge	Q_{gd}			7		nC
Drain-Source Diode Characteristics and Maximun Ratings						
Drain-Source Diode Forward Current [b]	I_S				-30	A
Drain-Source Diode Forward Voltage [c]	V_{SD}	V_{GS} = 0V, I_S = -20A			-1.2	V

Notes :
a.Repetitive Rating : Pulse width limited by maximum junction temperature.
b.Surface Mounted on FR4 Board, t ≤ 10 sec.
c.Pulse Test : Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
d.Guaranteed by design, not subject to production testing.

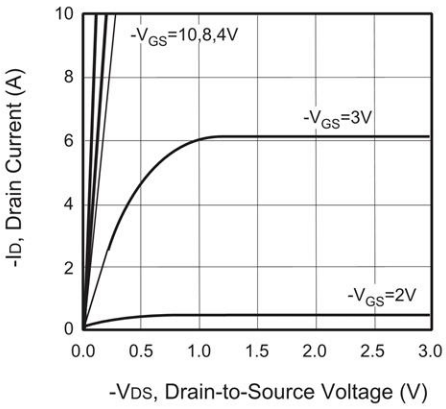


Figure 1. Output Characteristics

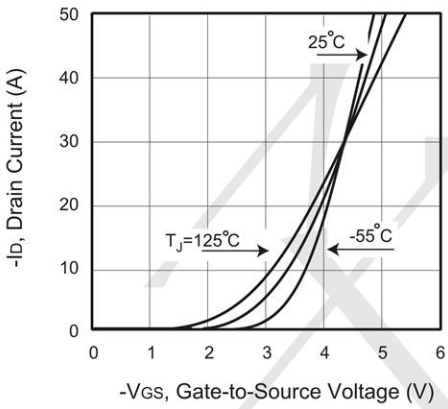


Figure 2. Transfer Characteristics

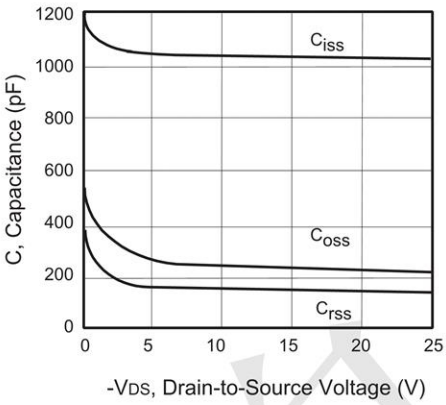


Figure 3. Capacitance

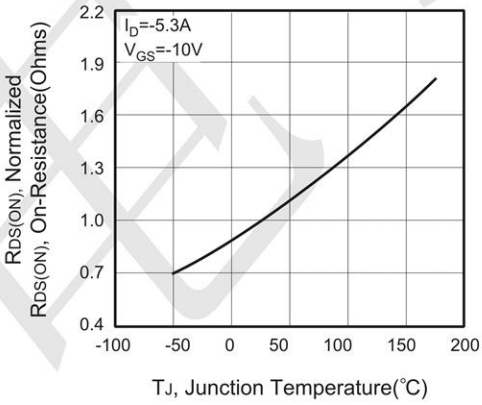


Figure 4. On-Resistance Variation with Temperature

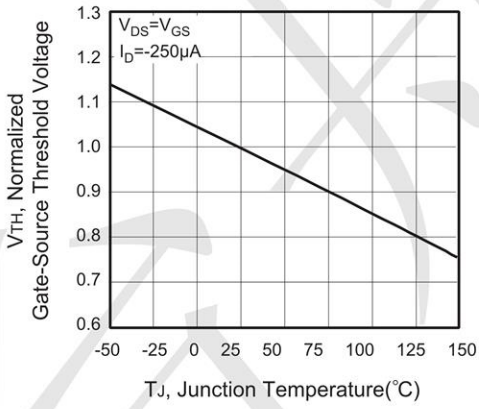


Figure 5. Gate Threshold Variation with Temperature

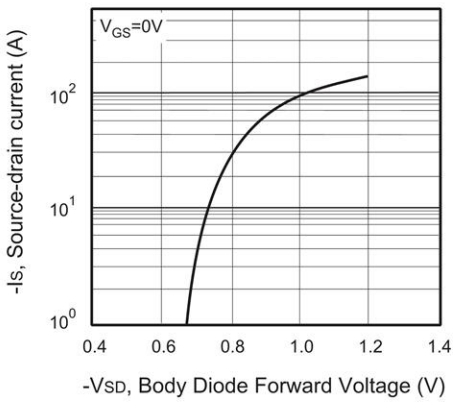


Figure 6. Body Diode Forward Voltage Variation with Source Current

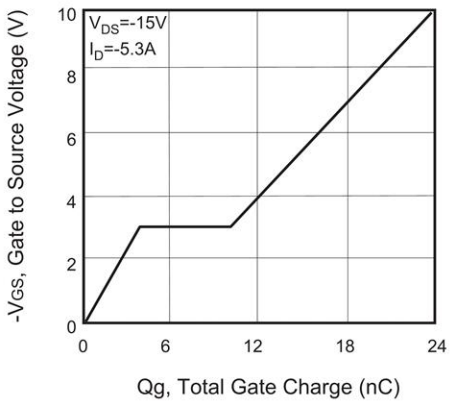


Figure 7. Gate Charge

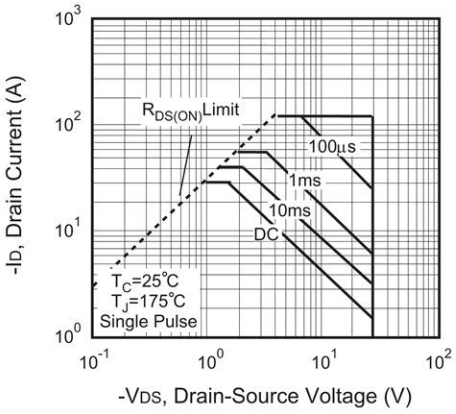


Figure 8. Maximum Safe Operating Area

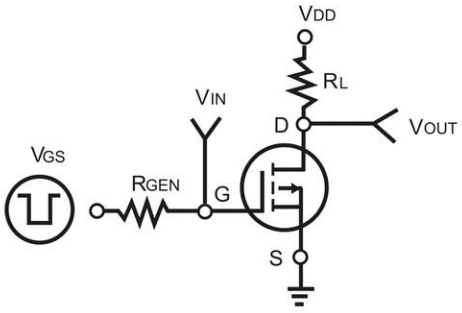


Figure 9. Switching Test Circuit

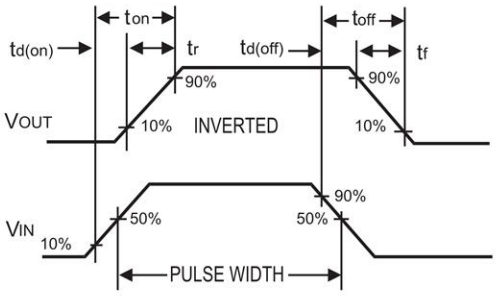


Figure 10. Switching Waveforms

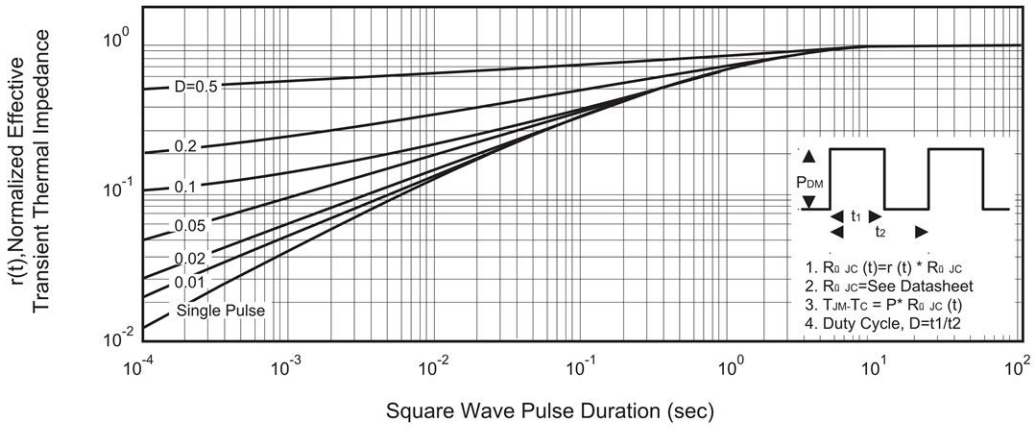
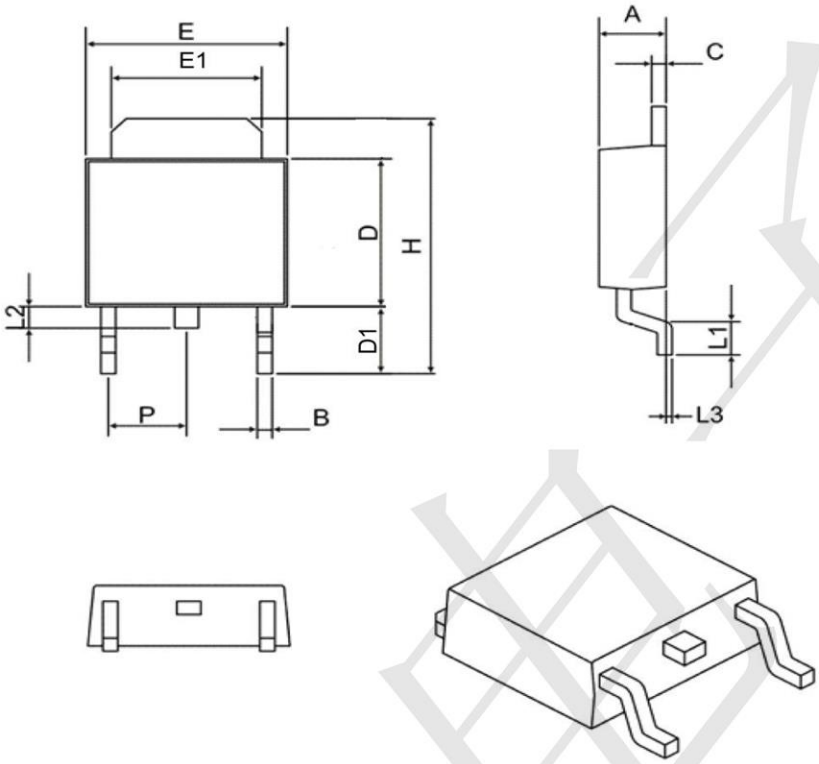


Figure 11. Normalized Thermal Transient Impedance Curve

TO252 Package Information



SYMBOL	MIN	MAX
A	2.10	2.50
B	0.40	0.90
C	0.40	0.90
D	5.30	6.30
D1	2.20	2.90
E	6.30	6.75
E1	4.80	5.50
L1	0.90	1.80
L2	0.50	1.10
L3	0.00	0.20
H	8.90	10.40
P	2.30 BSC	

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